Hydrogen internal friction peak and thermal desorption spectrum in amorphous $Cu_{60}Zr_{40}$

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Abstract

The hydrogen internal friction peak (HIFP) and hydrogen thermal desorption (HTD) in amorphous $Cu_{60}Zr_{40}$ were investigated for hydrogen concentrations $C_{H} \leq 45$ at.%. The C_{H} dependence of the HIFP suggests the following. The site energy (G) distribution for the Zr_4 sites can be explained as a single gaussian distribution $N_1(G)$. In contrast, the G distribution for the Zr_3Cu_1 sites is composed of two constituents $N_2(G)$ and $N_3(G)$. These features are very similar to those reported in amorphous $Cu_{50}Zr_{50}$ after taking into account the change in chemical composition, suggesting that $N_2(G)$ and $N_3(G)$ correspond to Zr_3Cu_1 sites with different next-nearestneighbour atoms. The HTD results suggest that in amorphous $Cu_{60}Zr_{40}$ hydrogen-induced structural relaxation proceeds below 650 K for $C_H \leq 8$ at.%.

1. Introduction

It is widely accepted that in an early transition metal-later transition metal (ETM-LTM) amorphous alloy A-B hydrogen mostly occupies tetrahedral sites, where the sequence of site energies G is determined by the number of LTM atoms, *i.e.* the B₄, B₃A₁, B₂A₂, B₁A₃ and A₄ sites with increasing G or increasing hydrogen concentration $C_{\rm H}$ [1-6]. Because of the structural disorder in amorphous alloys (a-alloys), G for each tetrahedron B_hA_{4-h} is expected to vary, reflecting the variation in atomic distances. If this effect can be described by a gaussian distribution [1], N(G) in $a - A_{1-x}B_x$ can be given by

$$N(G) = f_0 \sum_{h=0}^{4} \frac{4!}{h!(4-h)!} x^h (1-x)^{4-h} \\ \times \frac{1}{\sigma_h \pi^{1/2}} \exp\left[-\left(\frac{G-G_h}{\sigma_h}\right)^2\right]$$
(1)

where the a-alloy is assumed to be structurally isomorphic and chemically random [5]. f_0 denotes the occupation factor, *i.e.* the number of H atoms per metal atom, reflecting a blocking effect around occupied sites which is assumed here to be constant for any G. G_h and σ_h are the mean value and dispersion of G for the $B_h A_{4-h}$ sites respectively. When the difference between successive G_h values is larger than σ_h , N(G)shows five maxima with increasing G. C_H can be related to N(G) by

$$C_{\rm H} = \int_{0}^{\infty} \frac{N(G)}{1 + \exp[(G - \mu)/k_{\rm B}T]} \, \mathrm{d}G \approx \int_{0}^{\mu} N(G) \, \mathrm{d}G \qquad (2)$$

where $k_{\rm B}$ denotes the Boltzmann factor and T the temperature. Experimentally, most data for the H content in ETM-LTM a-alloys in the higher $C_{\rm H}$ range are well explained by eqns. (1) and (2) assuming that H occupies those sites under nearest-neighbour blocking [5, 6], *i.e.* $f_0 \approx 1.6$ at x = 0.5 [6]. For the lower $C_{\rm H}$ range, studies of the hydrogen internal friction peak (HIFP) in a-Ni₃₅Ti₆₅ [7], a-Cu₅₀Ti₅₀ [8, 9] and a-Cu₅₀Zr₅₀ [10] also support the view of nearest-neighbour blocking. That is, it is suggested that only H atoms occupying sites with site energy $G \approx \mu$ can contribute to hydrogen diffusion in a-alloys, where the total relaxation strength S₁ of the HIFP reflects $N(\mu)$ and the profile of the HIFP reflects a distribution of activation energies E, $n(E; \mu)$, for reorientation jumps of H atoms between sites with $G \approx \mu$. The HIFP studies on a-Cu₅₀Zr₅₀ [10] and a-Cu₅₀Ti₅₀ [8, 9] further suggest the following. N(G)for the Zr_4 (or Ti_4) sites can be explained by a single gaussian distribution $N_1(G)$, where the H content attained shows good agreement with the corresponding value expected from eqn. (1). In contrast, N(G) for the Zr_3Cu_1 (Ti₃Cu₁) sites appears to be composed of two constituents $N_2(G)$ and $N_3(G)$, where the total H content in both $N_2(G)$ and $N_3(G)$ shows good agreement with the H content for the Zr_3Cu_1 (Ti₃Cu₁) sites expected from eqn. (1). The distribution $n(E; \mu)$ is found to be composed of several constituent gaussian distributions $n_m(E; \mu)$ (m=0-6 for $a-Cu_{50}Zr_{50}$ or m=0-5 for $a-Cu_{50}Ti_{50}$), where differences between neighbouring mean activation energies E_m are larger than the dispersion β_m of E. To clarify whether these characteristic features found for the HIFP reflect a common property of ETM-LTM a-alloys, we further investigated the $C_{\rm H}$ dependence of the HIFP in $a-Cu_{60}Zr_{40}$ here. Separately we also investigated the hydrogen thermal desorption (HTD) [9-12] from $a-Cu_{60}Zr_{40}$ in ref. 13 to gain insight into N(G) on the G scale, which will be discussed together with the HIFP results.

2. Experimental procedures

Amorphous $Cu_{60}Zr_{40}$ was prepared by melt spinning in a high purity Ar gas atmosphere. Hydrogen charging was done electrolytically and then the specimens were mechanically polished in water to remove the surface layer. The size of the specimens was about 10 μ m×1 $mm \times 10$ mm. The hydrogenated specimens were aged for a few days at room temperature (RT) to homogenize $C_{\rm H}$ in them and then subjected to HIFP measurements. After the HIFP measurements the specimens were subjected to vacuum extraction to determine $C_{\rm H}$ [13]. The HIFP was measured using the resonant flexural vibration of about 500 Hz of specimens with a strain amplitude of 10^{-6} , where the resonant frequency $f\alpha$ $M^{1/2}$ and the internal friction Q^{-1} were almost continuously measured against temperature T, where Mis the Young modulus of the specimens (see refs. 8-10 for the detailed measuring procedures).

3. Results and discussion

Figure 1 shows examples of the HIFP observed in a-Cu₆₀Zr₄₀ specimens with various $C_{\rm H} \leq 32$ at.% (100[H]/ [metal]). The HIFP is observed as a very broad peak over the entire T range below 350 K, exhibiting a maximum between about 200 and 320 K. Q^{-1} in the a-Cu₆₀Zr₄₀ specimen without hydrogen charging is very low, except for a trace of the HIFP at RT due to H which was possibly absorbed into the specimen during polishing. After H charging, the HIFP maximum grows at around 320 K at first, then shows a repetition of decrease and increase as well as a general tendency of decreasing T at the HIFP maximum (T_{HIFP}) with increasing $C_{\rm H}$. The general features of both the HIFP and the $C_{\rm H}$ dependence of the HIFP found in a-Cu₆₀Zr₄₀ are very similar to those reported in a-Cu₅₀Zr₅₀ [10] and a-Cu₅₀Ti₅₀ [9], including the features for $n(E; \mu)$ (not shown here), when they are compared on the N(G) scale given in eqn. (1), except for the following. In a-Cu₆₀Zr₄₀, with increasing $C_{\rm H}$, $\Delta T/T_{\rm HIFP}$ decreases



Fig. 1. Hydrogen internal friction peak observed at about 500 Hz in a-Cu₆₀Zr₄₀ specimens with various hydrogen concentrations $C_{\rm H}$ (at.%): 1, \approx 0; 2, 3.9; 3, 6.0; 4, 8.7; 5, 10.3; 6, 15.9; 7, 22.2; 8, 31.6.

from about 0.41 at the middle of $N_1(G)$ to about 0.40 at the middle of $N_2(G)$, and T_{HIFP} at the middle of $N_1(G)$ decreases by about 16% at the middle of $N_2(G)$, where $\Delta T/T_{\text{HIFP}}$ is the width of the HIFP at halfmaximum normalized by T_{HIFP} (see Fig. 3 for $N_1(G)$ and $N_2(G)$). The corresponding $C_{\rm H}$ dependence reported is a decrease in $\Delta T/T_{\text{HIFP}}$ from about 0.42 to about 0.38 and a decrease in T_{HIFP} by about 10% in a-Cu₅₀Zr₅₀, and a decrease in $\Delta T/T_{HIFP}$ from about 0.60 to about 0.33 and a decrease in T_{HIFP} by about 8% in a-Cu₅₀Ti₅₀. That is, the features for $\Delta T/T_{HIFP}$ found in $a-Cu_{60}Zr_{40}$ are similar to those reported in $a-Cu_{50}Zr_{50}$ but different from those reported in a-Cu₅₀Ti₅₀, and the change in T_{HIFP} with increasing C_{H} is much larger in $a-Cu_{60}Zr_{40}$ than in $a-Cu_{50}Zr_{50}$ or $a-Cu_{50}Ti_{50}$. These results will be discussed later on.

In Fig. 2 the change in *M* between 5 and 350 K, $|\Delta M_{350 \text{ K}}/M|$, deduced from the observed change in *f* is plotted against S_t estimated from the observed HIFP (see refs. 9 and 10 for the estimation of S_t). The ordinary temperature change $|\Delta M_T/M|$ is found to be 0.07, which is almost the same as that reported in a-Cu₅₀Zr₅₀ or a-Cu₅₀Ti₅₀. We estimated the strength of the relaxation of the modulus associated with the HIFP, $|\Delta M_R/M|$, from $|\Delta M_{350 \text{ K}}/M|$ after the subtraction of $|\Delta M_T/M| = S_t$ can be seen as well as in a-Cu₅₀Zr₅₀ [10] and a-Cu₅₀Ti₅₀ [9], suggesting that the HIFP in these a-alloys can be well explained by a Debye relaxation process.

Figure 3 shows the $C_{\rm H}$ dependence of $S_{\rm t}$ observed in a-Cu₆₀Zr₄₀, where curves 1-4 are fitted to the data assuming that all the constituent distributions $N_1(G)$ to $N_4(G)$ are explained by a gaussian distribution. For $C_{\rm H}$ below about 2 at.% the HIFP is very low. We surmise that some Zr clusters existing even in the amorphous state as reported in a-Cu₂₄Zr₇₆ [5] are



Fig. 2. Modulus change $|\Delta M_{350 \text{ K}}/M|$ and that associated with HIFP, $|\Delta M_R/M|$, plotted vs. total relaxation strength S_t for HIFP observed in a-Cu₆₀Zr₄₀. The straight line is fitted to the data assuming the relationship $|\Delta M_R/M| = S_t$.



Fig. 3. S_t vs. C_H observed for HIFP in a-Cu₆₀Zr₄₀. See text for explanation of curves 1–4.

responsible for the very low HIFP below about 2 at.%. For $C_{\rm H}$ above about 2 at.%, besides the general $C_{\rm H}$ dependence of S_t estimated as curves 1–4, some scatter in the S_t data can be seen at C_H values of about 7 and 17 at.%, which will be mentioned later. As seen in Fig. 3, the H content attained in $N_1(G)$ is about 4 at.% and that in $N_2(G) + N_3(G)$ about 24 at.%. These show reasonable agreement with the H content of about 4 at.% in the Zr_4 sites and that of about 25 at.% in the Zr_3Cu_1 sites respectively expected from eqn. (1) assuming $f_0 \approx 1.6$ [6]. That is, similar features to those for $N_1(G)$ and $N_2(G) + N_3(G)$ reported in a-Cu₅₀Zr₅₀ [10] are again observed in a-Cu₆₀Zr₄₀. In a-Cu₅₀Zr₅₀ [10], $N_2(G)$ and $N_3(G)$ are surmised to correspond to Zr₃Cu₁ sites with different next-nearest-neighbour metal atoms. If that is the case, the relative H content for $N_3(G)/[N_2(G) + N_3(G)]$ is expected to be increased in a-Cu₆₀Zr₄₀ owing to an increased Cu content in the aalloy. In fact, the $N_3(G)/[N_2(G) + N_3(G)]$ value of about 22 at.%/37 at.% ≈ 0.6 reported in a-Cu₅₀Zr₅₀ increases to about 20 at.%/24 at.% ≈ 0.8 in a-Cu₆₀Zr₄₀ here.

Figure 4 shows examples of HTD spectra observed in a-Cu₆₀Zr₄₀ specimens at a heating rate of 1.6 K s⁻¹, which are a redrawing of Fig. 4 reported in ref. 13. The vertical dashed line denotes the crystallization temperature T_x found for a-Cu₆₀Zr₄₀ specimens at a heating rate of 1.6 K s⁻¹. As seen in Fig. 4, HTD below T_x is very low for $C_H \leq 8$ at.%. For $C_H \geq 8$ at.% an HTD peak at around 750 K grows at first, then shows a strong decrease at about 18 at.%. For $C_{\rm H} \ge 18$ at.% an HTD peak is again observed at around 750 K but with a different feature. The growth followed by a decrease in the HTD peak below T_x is also observed for a small HTD peak at around 660 K between about 28 and 34 at.% as well as for a broad HTD peak at around 600 K between about 38 and 48 at.%. The decrease after the growth of the HTD peaks is found to be due to partial crystallization during heating, *i.e.* its onset temperature $T_{x,s}$ decreases with increasing $C_{\rm H}$ in a-Cu₆₀Zr₄₀ [13] (see also ref. 14). Apart from $T_{x,s}$, we observed that HTD below T_x is very low for $C_H \leq 8$ at.%, where an HTD peak from the Zr_4 sites can be expected at around 650 K as reported for a-Cu₅₀Zr₅₀



Fig. 4. Hydrogen thermal desorption spectra observed at a heating rate of 1.6 K s⁻¹ for a-Cu₆₀Zr₄₀ specimens with various hydrogen concentrations $C_{\rm H}$ as indicated. The vertical dashed line denotes the crystallization temperature for the a-Cu₆₀Zr₄₀ specimen without hydrogen charging; here $T_{\rm x} \approx 815$ K at a heating rate of 1.6 K s⁻¹.

[13]. This fact suggests that H-induced structural relaxation (HISR) proceeds below 650 K in $a-Cu_{60}Zr_{40}$ for $C_{\rm H} \leq 8$ at.%. In a-Cu₅₀Zr₅₀ the following is reported [13]. $T_{x,s}$ hardly shows a deviation from T_x for this aalloy for $C_{\rm H} \leq 40$ at.%, but HISR proceeds intermittently on the $C_{\rm H}$ scale, showing a decrease in the onset temperature for HISR with increasing $C_{\rm H}$ down to RT at $C_{\rm H} \approx 25$ at.%. Correspondingly, the $S_{\rm t}$ vs. $C_{\rm H}$ data for the HIFP in a-Cu₅₀Zr₅₀ show some deviatory scattering from the proper $C_{\rm H}$ dependence of $S_{\rm t}$ [10]. Therefore we tentatively surmise that the deviatory scattering from the proper $C_{\rm H}$ dependence of $S_{\rm t}$ observed in a-Cu₆₀Zr₄₀ (see Fig. 3) presumably reflects the effect of HISR. However, the fact that for both a-Cu₆₀Zr₄₀ and a-Cu₅₀Zr₅₀ the hydrogen content for $N_1(G)$ and $N_2(G) + N_3(G)$ can be well explained by eqn. (1) suggests that the densities of sites for $N_1(G)$ and $N_2(G) + N_3(G)$ remain unchanged after HISR.

The results for $\Delta T/T_{\rm HIFP}$ mentioned in connection with Fig. 1 suggest that for both a-Cu₆₀Zr₄₀ and a-Cu₅₀Zr₅₀ the variations in atomic distances in Zr₄ tetrahedra are similar to those in Zr₃Cu₁ tetrahedra, but for a-Cu₅₀Ti₅₀ those in Ti₄ tetrahedra are much larger than those in Ti₃Cu₁ tetrahedra. On the other hand, because the relative change in $T_{\rm HIFP}$ between the HIFP for the Zr₄(Ti₄) sites and the HIFP for the Zr₃Cu₁(Ti₃Cu₁) sites is much larger in a-Cu₆₀Zr₄₀ than in a-Cu₅₀Zr₅₀ or a-Cu₅₀Ti₅₀, we surmise that it reflects a change in the number of Cu atoms as next-nearestneighbour atoms around these sites. To clarify these issues, however, further work is needed.

4. Conclusions

The hydrogen internal friction peak and hydrogen thermal desorption in a-Cu₆₀Zr₄₀ were investigated. The $C_{\rm H}$ dependence of the HIFP suggests the following. The site energy (G) distribution for the Zr₄ sites can be explained as a single gaussian distribution $N_1(G)$, while that for the Zr₃Cu₁ sites is composed of two constituents $N_2(G)$ and $N_3(G)$. These features are very similar to those reported in a-Cu₅₀Zr₅₀, suggesting that $N_2(G)$ and $N_3(G)$ correspond to Zr₃Cu₁ sites with different next-nearest-neighbour atoms. The HTD results suggest that in a-Cu₆₀Zr₄₀, hydrogen-induced structural relaxation proceeds below 650 K for $C_{\rm H} \leq 8$ at.%.

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